

# DIDR10150

## **1500V 10A DAMPER RECTIFIER DIODE**

#### **Features**

- Glass Passivated Die Construction
- Diffused Junction
- Super-Fast Recovery Times for High Efficiency
- High Current Capability and Low Forward Voltage Drop
- Surge Overload Rating to 50A Peak
- Low Reverse Leakage Current
- Plastic Material: UL Flammability Classification Rating 94V-0

#### **Mechanical Data**

- Case: Molded Plastic
- Terminals: Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Weight: 3.0 grams (approx.)



ITO-220AC			
Dim	Min	Max	
Α	14.8	15.4	
в	9.6	10.3	
С	2.55	2.85	
D	6.3	6.9	
Е	_	4.1	
G	13.0	13.8	
J	.5	.9	
К	3.0	3.4	
L	3.5	4.8	
М	2.3	3.1	
Ν	.4	.8	
Р	2.5	2.9	
R	4.83	5.33	
All Dimensions in mm			

### Maximum Ratings and Electrical Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic		DIDR10150	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		1500	v
RMS Reverse Voltage		1060	V
Average Rectified Output Current		10	Α
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)		50	А
Forward Voltage @ I <sub>F</sub> = 10A	V <sub>FM</sub>	2.8	V
$ \begin{array}{lll} \mbox{Peak Reverse Current} & \mbox{@} \ T_C = \ 25^\circ C \\ \mbox{at Rated DC Blocking Voltage} & \mbox{@} \ T_J = \ 90^\circ C \\ \end{array} $	I <sub>RM</sub>	50 500	μA
Maximum Recovery Time (Note 1) (Note 2)		200 500	ns
Typical Junction Capacitance (Note 3)		50	pF
Typical Thermal Resistance Junction to Lead 1/8" From Body		25	°C/W
Operating and Storage Temperature Range		-65 to +125	°C

Notes: 1. Measured with  $I_F = 0.5A$ ,  $I_R = 1.0A$ ,  $I_{rr} = 0.25A$ .

- 2. Measured with  $I_F$  = 0.5A,  $\ I_R$  = 0.5A 90% Recovery Point
- 3. Measured at 1.0 MHz and Applied Reverse Voltage of 4.0V DC.



